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	Ti)O3Fourier Harmonic Analysis of the Electromechanical Response of Electroactive Materials; High Curie Temperature, High Performance Perovskite Single Crystals in the Pb(Yb1/2Nb1/2)O3-PbTiO3 and BiScO3-PbTiO3 Systems; Electromechanical Performance Advantages and Limitations of - Oriented Pb(Mg1/3Nb2/3)O3-PbTiO3 Crystals; Polarization Induced Cracking in Partially Electroded PSZT Ceramic; Acceptor Doped PZN-PT Single Crystals; Structure and Dielectric Properties in Novel BiGaO3-PbTiO3 Crystalline Solutions Preparation and Electrical Properties of Pb(In1/2Nb1/2)O3 Based Relaxor MaterialsComposition and Sintering Process Effects on Ferroelectric Fatigue in (1-x)Pb(Mg1/3Nb2/3)O3-x PbTiO3 Ceramics; Sintering Behavior of Additive Free (Pure) Lead Metaniobate Ceramics; Electroceramic Fibers for Active Control; Influence of Hot-Pressing Parameters in Microstructure Evolution of PBN on Morphotropic Phase Boundary; Synthesis of High Strain Piezoelectric Crystals and Textured Ceramics; Feasibility of the Growth of Relaxor-Based Ferroelectric Single Crystals Two Inches Size Single Crystal Growth of Piezoelectric Pb[(Zn1/3Nbl/3) 0.91Ti0.09]O3 by the Solution Bridgman MethodImproved Dielectric And Piezoelectric Properties of Pb(Mg1/3Nb2/3)O3-32.5PbTiO3 Ceramics and [001]Textured PMN-PT; Laser Heated Pedestal Growth of Lead Magnesium Niobate - Lead Titanate Crystals and Their Characterization; Effect of Li2O and PbO Additions on Abnormal Grain and Single Crystal Growth in the Pb(Mg1/3Nb2/3)O3-35 MOL% PbTiO3 System; High Aspect Ratio Platelet SrTiO3 for Templated Grain Growth of PMN-PT Ceramics Synthesis of PMN and 65PMN-35PT Ceramics and Films by a New Suspension MethodDielectric Materials Development and Device Fabrications; Microwave Properties of Low-Temperature Co-Fired Ceramic Systems*; Near-Zero Tf Doped-Niobate Ceramics for Dielectric Resonator Applications; Low-T Sintering, Low-Dielectric Materials for High Frequency Ceramic Multilayer Parts; Low-Inductance Barium Strontium Titanate Thin Film Capacitors for Decouplin
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